

N-Channel Silicon MOSFET

# 2SK2864

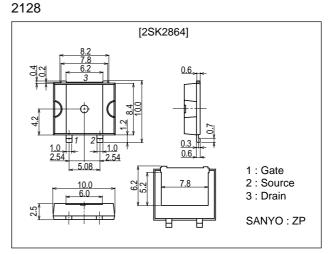
# **Ultrahigh-Speed Switching Applications**

### Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- Enables simplified fabrication, high-density mounting, and miniaturization in end products due to the surface mountable package.

## Package Dimensions

unit : mm



# **Specifications**

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		200	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		20	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	80	А
Allowable Power Dissipation	PD	Tc=25°C	50	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	200			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	I <sub>G</sub> =±100μA, V <sub>DS</sub> =0	±20			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =200V, V <sub>GS</sub> =0			100	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	2.0		4.0	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =10A	6	10		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)	I <sub>D</sub> =10A, V <sub>GS</sub> =10V		90	120	mΩ

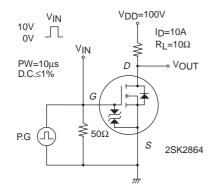
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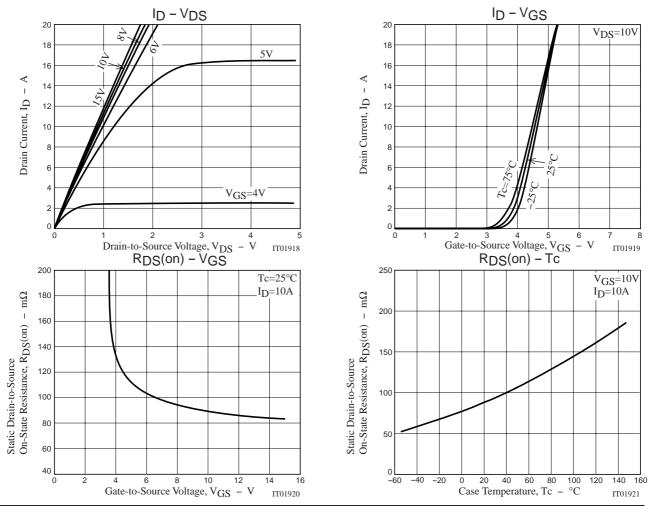
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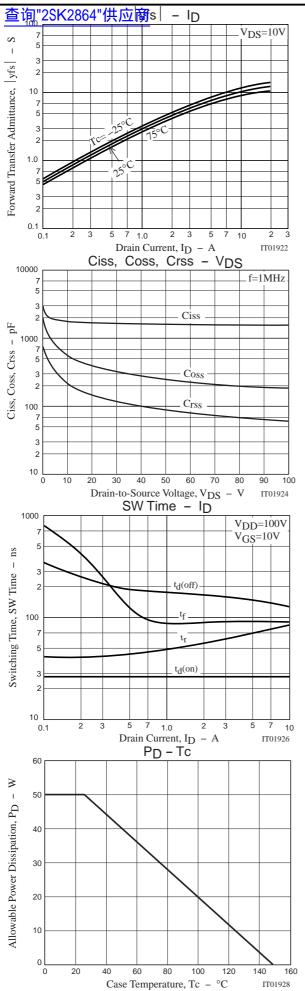
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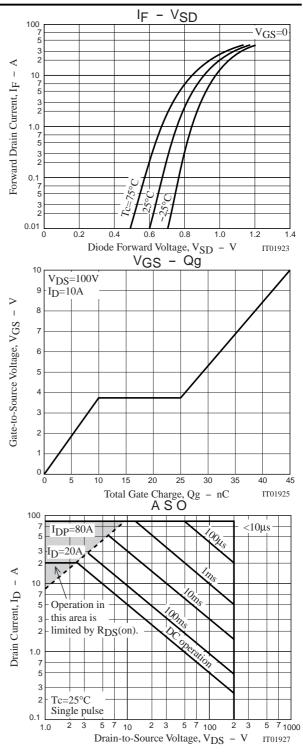
Parameter	Symbol	Conditions	Ratings			Linit
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss1	V <sub>DS</sub> =0, f=1MHz		3000	3800	pF
	Ciss2	V <sub>DS</sub> =20V, f=1MHz		1700	2150	pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		400	420	pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		150	185	pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit		28	35	ns
Rise Time	tr	See specified Test Circuit		85	110	ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit		130	165	ns
Fall Time	tf	See specified Test Circuit		90	105	ns
Diode Forward Voltage	VSD	IS=20A, VGS=0		1.0	1.5	V
Gate resistance	Rg	f=1MHz	1.0	2.0	3.0	Ω

## Switching Time Test Circuit









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